

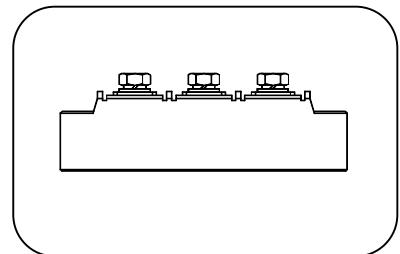
MDG150 MDY150

Diode Modules(Non-isolated type)

Features:

- Non-Isolated. Mounting base as common anode cathode terminal.
 - Pressure contact technology with Increased power cycling capability
 - Low forward voltage drop
- Typical Applications**
- Welding Power Supply
 - Various Dc power supplies.

$I_{F(AV)}$	150 A
V_{RRM}	800~1800 V
I_{FSM}	5.8 A $\times 10^3$
I^2t	171.5 A ² s $\times 10^3$



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, $T_c=100^\circ\text{C}$	150			150	A
$I_{F(RMS)}$	RMS forward current		150			236	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms $V_{RSM}=V_{RRM}+200\text{V}$	150	800		1800	V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			12	mA
I_{FSM}	Surge forward current	10ms half sine wave	150			5.8	KA
I^2t	I^2T for fusing coordination	$V_R=0.6V_{RRM}$				171.5	A ² s*10 ³
V_{FO}	Threshold voltage		150			0.80	V
r_F	Forward slop resistance					1.53	mΩ
V_{FM}	Peak forward voltage	$I_{FM}=450\text{A}$	25			1.57	V
$R_{th(j-c)}$	Thermal resistance Junction to case	Single side cooled				0.240	°C /W
$R_{th(c-h)}$	Thermal resistance case to heatsink	Single side cooled				0.1	°C /W
F_m	Terminal connection torque(M6)				6		N·m
	Mounting torque(M6)				6		N·m
T_{stg}	Stored temperature			-40		125	°C
W_t	Weight				380		g
Outline	213F4						

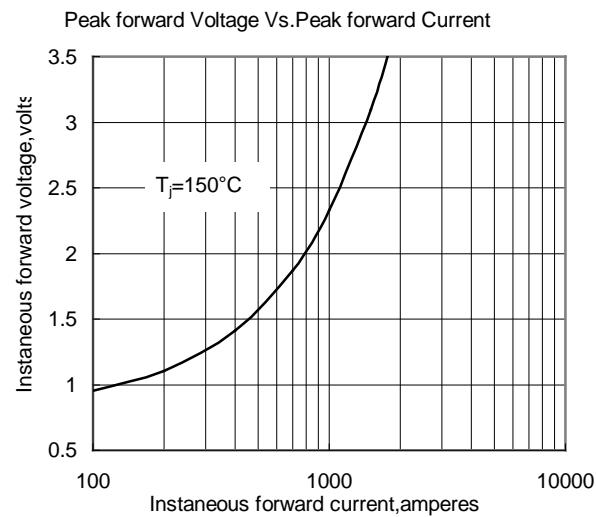


Fig.1

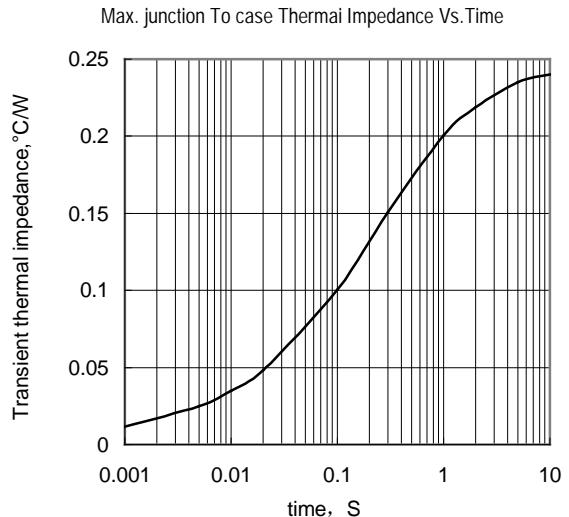


Fig.2

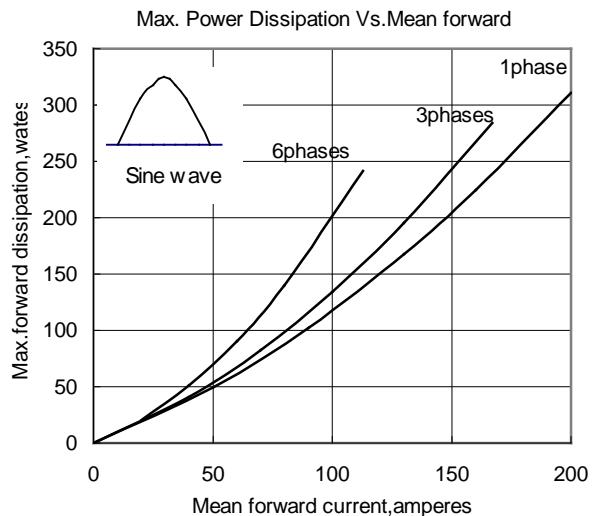


Fig.3

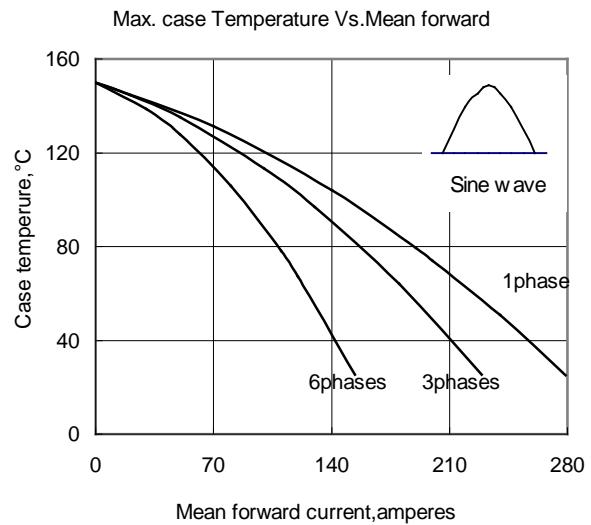


Fig.4

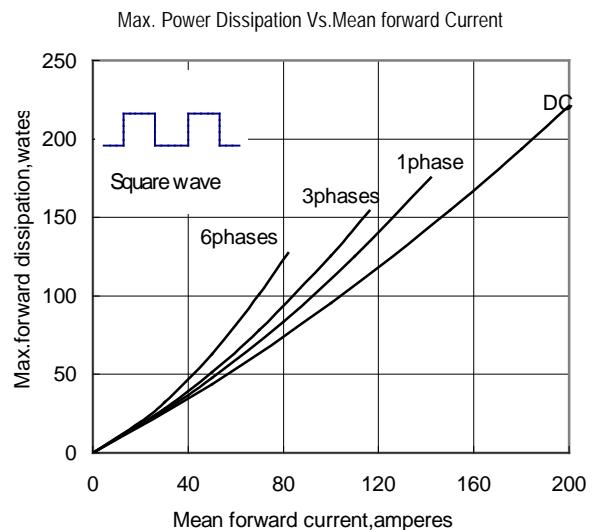


Fig.5

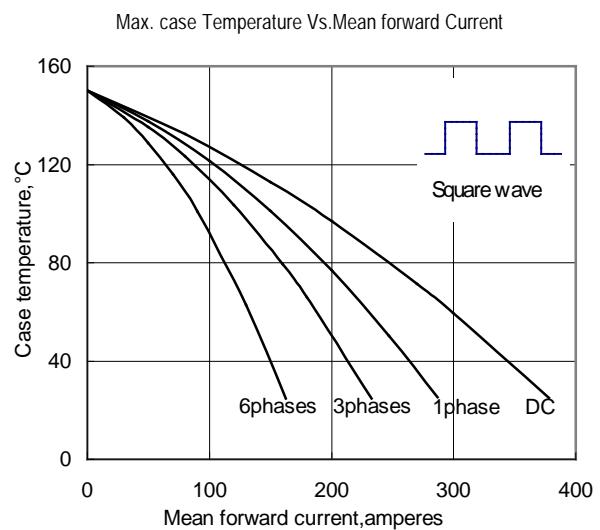


Fig.6

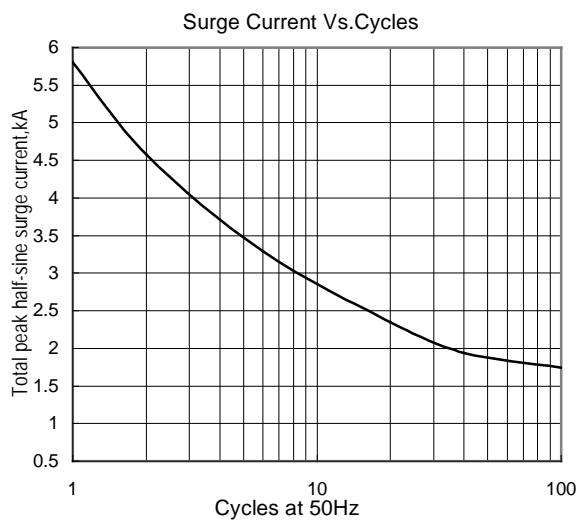


Fig.7

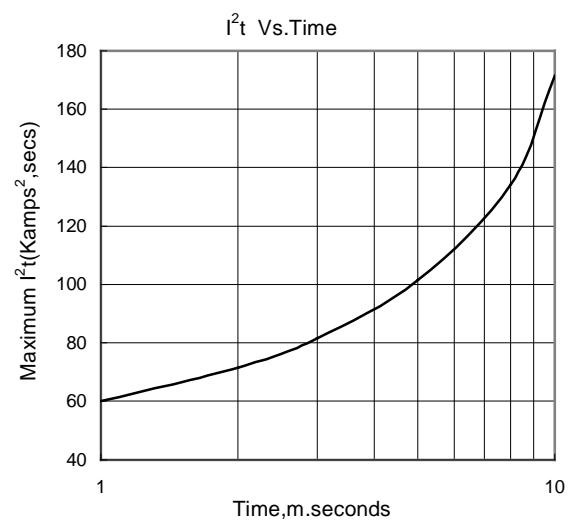
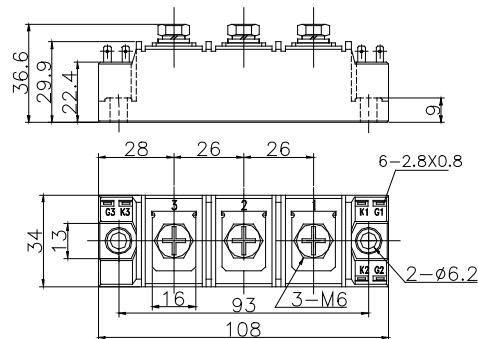


Fig.8

Outline:



213F4

